TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC540P,TC74AC540F,TC74AC540FW,TC74AC540FT TC74AC541P,TC74AC541F,TC74AC541FW,TC74AC541FT

Octal Bus Buffer

TC74AC540P/F/FW/FT

Inverting, 3-State Outputs

TC74AC541P/F/FW/FT

Non-Inverting, 3-State Outputs

The TC74AC540/TC74AC541 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74AC540 is an inverting type, and the TC74AC541 is a non-inverting type.

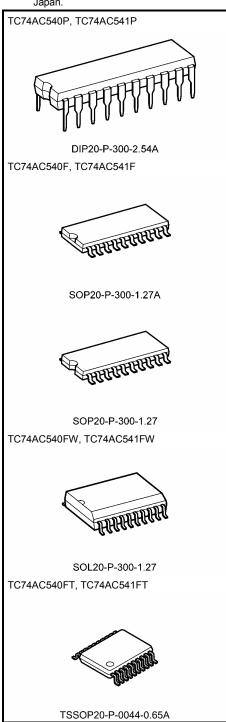
When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 4.0 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- \bullet Pin and function compatible with 74F540/541

Note: xxxFW (JEDEC SOP) is not available in Japan.



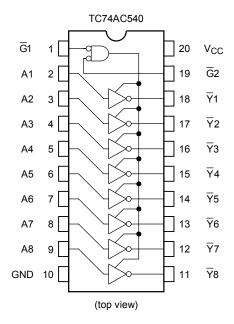
Weight

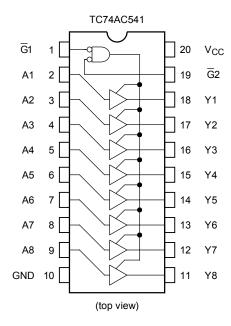
DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.)

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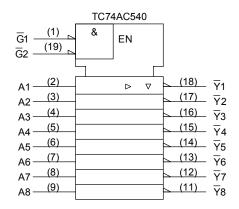


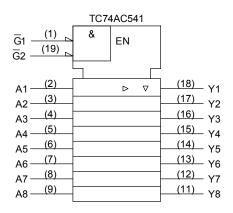
Pin Assignment





IEC Logic Symbol





Truth Table

	Inputs	Outputs				
G1	G2	A _n	Yn	\overline{Y}_n		
Н	Х	Х	Z	Z		
Х	Н	Х	Z	Z		
L	L	Н	Н	L		
L	L	L	L	Н		

X: Don't care

Z: High impedance

 Y_n : AC541 \overline{Y}_n : AC540



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±200	mA
Power dissipation	P _D	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
imput rise and rail time	u.uv	0 to 20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)		

Note: The recommended operating conditions are required to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics Symb		Test Condition			Ta = 25°C		Ta = -40 to 85°C		- Unit		
Ondiacteristics Syl	Symbol				V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
		-		2.0	1.50	_	_	1.50	_	٧	
High-level input voltage	V _{IH}			3.0	2.10	_	_	2.10	_		
				5.5	3.85	_	_	3.85	_		
		_		2.0	_	_	0.50	_	0.50	٧	
Low-level input voltage	V _{IL}			3.0	_	_	0.90	_	0.90		
					5.5	_	_	1.65	_	1.65	
					2.0	1.9	2.0	_	1.9	_	. V
			I _{OH} = -50 μA		3.0	2.9	3.0	_	2.9	_	
High-level output	V	V _{IN} = V _{IH} or V _{IL}			4.5	4.4	4.5	_	4.4	_	
voltage	V _{OH}		I _{OH} = -4 mA		3.0	2.58	_	_	2.48	_	
			I _{OH} = -24 mA		4.5	3.94	_	_	3.80	_	
			I _{OH} = -75 mA	(Note)	5.5	_	_	_	3.85	_	
		V _{IN} = V _{IH} or V _{IL}			2.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 50 μA		3.0	_	0.0	0.1	_	0.1	
Low-level output	\/-·				4.5	_	0.0	0.1	_	0.1	
voltage	V _{OL}		I _{OL} = 12 mA		3.0	_	_	0.36	_	0.44	
			I _{OL} = 24 mA		4.5	_	_	0.36	_	0.44	
			I _{OL} = 75 mA	(Note)	5.5	_	_	_	_	1.65	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	_	±0.5	_	±5.0	μΑ	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	_	_	±0.1	_	±1.0	μА	
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	8.0	_	80.0	μΑ	

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Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	.,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t _{pLH}		3.3 ± 0.3	_	6.8	10.5	1.0	12.0	ns
time (Note 2)	t_{pHL}	_	5.0 ± 0.5	_	4.7	7.0	1.0	8.0	115
Propagation delay	t _{pLH}		3.3 ± 0.3	_	6.8	11.4	1.0	13.0	ns
time (Note 3)	t_{pHL}	_	5.0 ± 0.5	_	4.7	7.5	1.0	8.5	
Output enable time	t _{pZL}	_	3.3 ± 0.3	_	9.6	15.8	1.0	18.0	ns
	t_{pZH}		5.0 ± 0.5	_	6.4	10.0	1.0	11.4	
Output disable time	t _{pLZ}		3.3 ± 0.3	_	7.7	12.3	1.0	14.0	ns
	t_{pHZ}	_	5.0 ± 0.5	_	6.4	9.2	1.0	10.5	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Output capacitance	C _{OUT}	_		_	10	_	_	_	pF
Power dissipation capacitance	C _{PD}	TC74AC540		_	25	_	_	_	
	(Note 1)	TC74AC541		_	28	_	_	_	pF

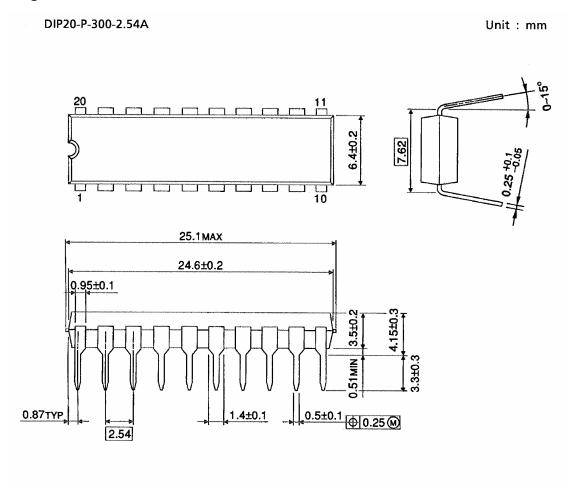
Note1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$

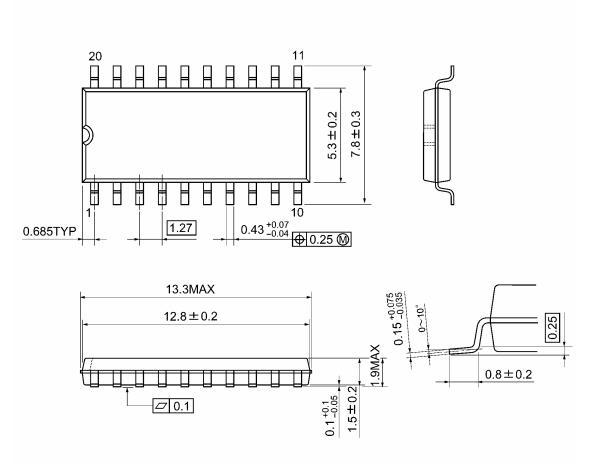
Note 2: For TC74AC540 only Note 3: For TC74AC541 only





Weight: 1.30 g (typ.)

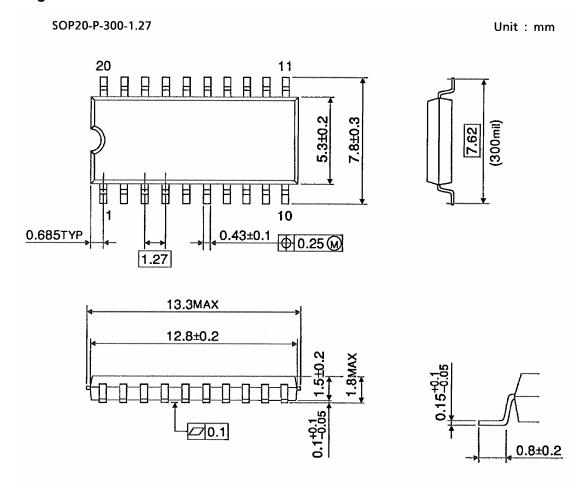
SOP20-P-300-1.27A Unit: mm



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Weight: 0.22 g (typ.)

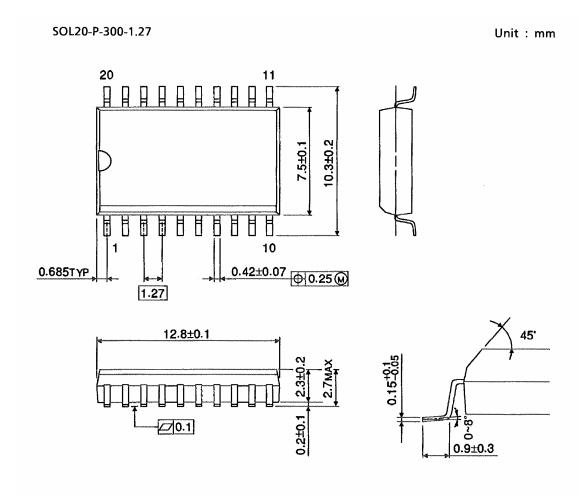




Weight: 0.22 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

TSSOP20-P-0044-0.65A Unit: mm 6.4±0.2 $0.22\substack{+0.09 \\ -0.06}$ 0.65 0.325TYP **⊕**0.13**M** 6.9MAX 6.5±0.1 1.2MAX 0.15 +0.03 0~10 1.0±0.05 0.1±0.05 S Ø.1|S (0.5)

Weight: 0.08 g (typ.)

0.45~0.75

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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